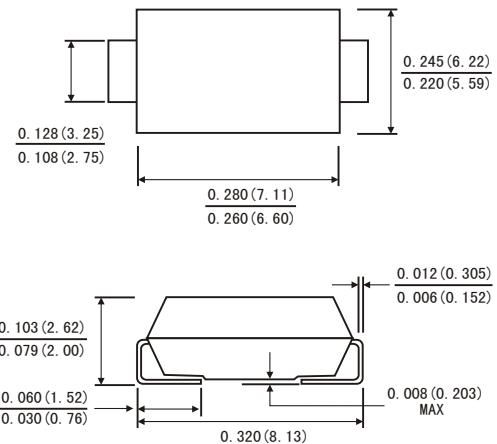


## FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction ,majority carrier conduction
- For surface mount applications
- Low power loss ,high efficiency
- High current capability ,low forward voltage drop
- Low profile package
- Built-in strain relief ,ideal for automated placement
- For use in low voltage ,high frequency inverters, free wheeling ,and polarity protection applications
- High temperature soldering guaranteed:260°C/10 seconds at terminals
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC


**SMC(DO-214AB)**


Dimensions in inches and (millimeters)

## MECHANICAL DATA

- Case: JEDEC SMC(DO-214AB) molded plastic body
- Terminals: solder plated ,solderable per MIL-STD-750,method 2026
- Polarity: color band denotes cathode end
- Weight: 0.007ounce,0.21 gram

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Ratings at 25 °C ambient temperature unless otherwise specified ,Single phase ,half wave ,resistive or inductive load. For capacitive load, derate by 20%.)

	Symbols	SS 52	SS 53	SS 54	SS 55	SS 56	SS 58	SS 5A	Units
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	20	30	40	50	60	80	100	Volts
Maximum RMS voltage	V <sub>RMS</sub>	14	21	28	35	42	57	71	Volts
Maximum DC blocking voltage	V <sub>DC</sub>	20	30	40	50	60	80	100	Volts
Maximum average forward rectified current 0.375"(9.5mm) lead length(see fig.1)	I <sub>(AV)</sub>				5.0				Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method at rated T <sub>J</sub> )	I <sub>FSM</sub>				150.0				Amps
Maximum instantaneous forward voltage at 5.0 A(Note 1 )	V <sub>F</sub>		0.55		0.75	0.80	0.85		Volts
Maximum instantaneous reverse current at rated DC blocking voltage voltage(Note 1)	I <sub>R</sub>	T <sub>A</sub> =25°C T <sub>A</sub> =100°C			1.5				mA
			20		10				
Typical junction capacitance(Note 3)	C <sub>J</sub>		500		400				PF
Typical thermal resistance (Note 2)	R <sub>θJA</sub> R <sub>θJL</sub>			55.0					°C/W
Operating junction temperature range	T <sub>J</sub>		-65 to +125		-65 to +150				°C
Storage temperature range	T <sub>STG</sub>			-65 to +150					°C

Notes: 1. Pulse test: 300 μ s pulse width,1% duty cycle

2. P.C.B. mounted 0.55X0.55"(14X14mm) copper pad areas

3. Measured at 1MHz and reverse voltage of 4.0 volts

# RATINGS AND CHARACTERISTIC CURVES SS52-SS5A

FIG.1-FORWARD CURRENT DERATING CURVE

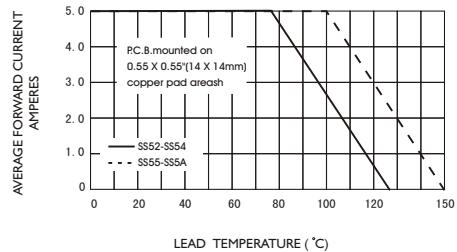


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

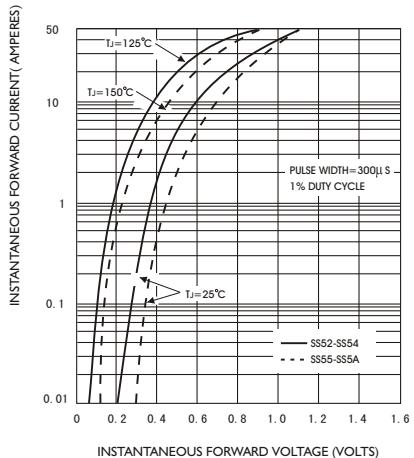


FIG.5-TYPICAL JUNCTION CAPACITANCE

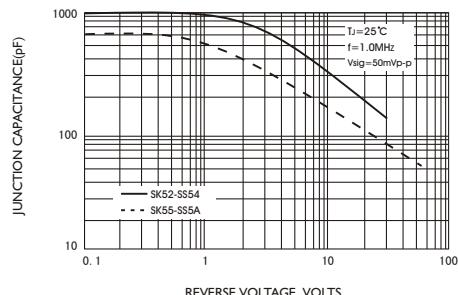


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

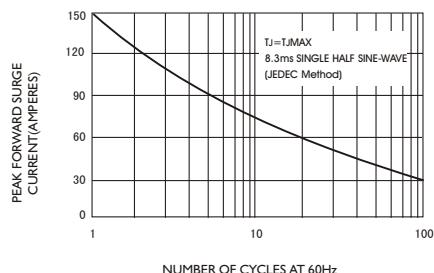


FIG.4-TYPICAL REVERSE CHARACTERISTICS

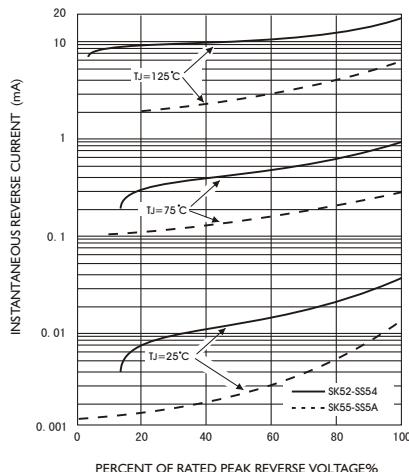


FIG.6-TYPICAL TRANSIENT THERMAL IMPEDANCE

